



Keithley's solutions for solar cell I-V and C-V characterization provide the most accurate measurements available without the hassles of integrating separate instruments or writing complicated programs.

Electrical characterization of a variety of solar cell (Photovoltaic) technologies, including:

- Mono Crystalline Si
- Poly Crystalline Si
- Amorphous Si
- CIGS
- Polymer Organic

· Cell resistivity

· Defect density

• Conversion efficiency (η)

Measurement of key parameters including:

- Open circuit voltage(Voc)
- Short circuit current (Isc)
- Maximum power output (Pmax) Doping density (N)
- Voltage at Pmax (Vmax)
- Fill factor (ff)
- Series resistance (Rs)

- CdTe

## Built-in libraries for extracting key cell parameters, and advanced analytical and formulation tools

## **SERIES 2400 OR 2600A** • Shunt resistance (Rsh) **SOURCEMETER® INSTRUMENTS**

**MODEL 4200-SCS** 

graphical user interface

■ 4-quadrant design provides both source and sink capability

**SEMICONDUCTOR CHARACTERIZATION SYSTEM** 

■ Fully integrated I-V and C-V turn key solution with intuitive

■ All-in-one solution for I-V characterization with the combined functionality of a precision power supply, high precision DMM, and electronic load



